ABSOLUTE MAXIMUM RATINGS

IN, GATE to GND0.3V to +30V	Operating Temperature Range40°C to +85°
FLAG to GND0.3V to +6V	Junction Temperature+150°
Continuous Power Dissipation ($T_A = +70^{\circ}C$)	Storage Temperature Range65°C to +150°
6-μDFN (derate 2.1mW/°C above 70°C)168mW	Lead Temperature (soldering, 10s)+300 °

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS

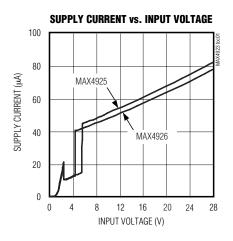
 $(V_{IN} = +5V \text{ for MAX4923/MAX4924/MAX4925}, V_{IN} = +4V \text{ for MAX4926}, C_{GATE} = 500pF \text{ to IN, } T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}\text{C}$.) (Note 1)

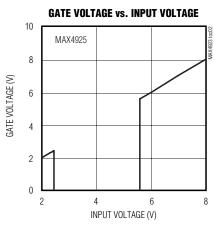
PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS	
Input Voltage Range	V _{IN}			1.8		28.0	V	
	OVLO		MAX4923	7.00	7.18	7.36	V	
Over teltage I palcout I avai		V _{IN} rising	MAX4924	6.00	6.16	6.31		
Overvoltage Lockout Level			MAX4925	5.50	5.65	5.79		
			MAX4926	4.35	4.46	4.57		
		MAX4923		65				
Overvelte see Leekevit Lhistoreeis		MAX4924			55		\/	
Overvoltage Lockout Hysteresis		MAX4925			50		mV	
		MAX4926			40		1	
Undervoltage Lockout Level	UVLO	V _{IN} falling		2.378	2.439	2.500	V	
Undervoltage Lockout Hysteresis					20		mV	
10.00		MAX4923/MAX4924/MAX4925			14	25	μΑ	
IN Supply Current	I _{IN}	MAX4926			13	23		
GATE Voltage High	V _{OH}	V _{IN} ≥ 8V, I _{SOURCE} = 0.1mA		V _{IN} - 0.2			V	
GATE Pulldown Current	IPD	VGATE = VIN		6.5	12		mA	
FLAG Low Voltage	Vol	ISINK = 1mA				0.4	V	
FLAG Leakage Current	I _{LKG}	VFLAG = 5.5V		-1		+1	μΑ	
TIMING CHARACTERISTICS								
Debounce Time	tDEB	V _{UVLO} < V _{IN} < V _{OVLO} , time for GATE to go low (Figure 1)		10	20	34	ms	
Gate Turn-on Time	tgon	V _{GATE} = 5V to 0.5V (MAX4923/MAX4924/MAX4925) or V _{GATE} = 4V to 0.5V (MAX4926) (Figure 1)			0.6		μs	
Gate Turn-Off Time	tgoff	V _{IN} rising at 1V/µs from 5V to 8V (MAX4923/MAX4924/MAX4925) or from 4V to 7V (MAX4926) to V _{GATE} = V _{IN} -0.5V (Figure 1)			5	20	μs	
Flag Assertion Delay	^t FLAG	V_{IN} rising at 1V μs from 5V to 8V (MAX4923/MAX4924/MAX4925) or from 4V to 7V (MAX4926), to V _{FLAG} = 2.4V, R _{FLAG} = 10k Ω to 3V (Figure 1)			4.5		μs	

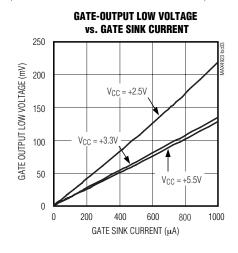
Note 1: All devices are 100% tested at +25°C. Electrical limits across the full temperature range are guaranteed by design and characterization.

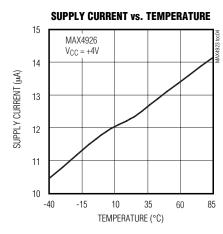
Typical Operating Characteristics

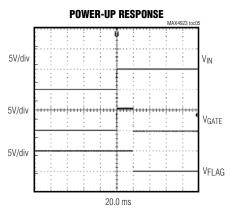
 $(V_{IN} = +5V \text{ for MAX4923/MAX4924/MAX4925}, V_{IN} = +4V \text{ for MAX4926 (pFET} = Si6991DQ), T_A = +25^{\circ}C, unless otherwise noted.)$

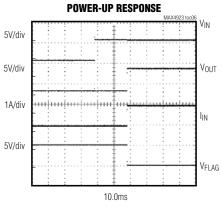


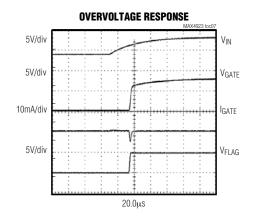


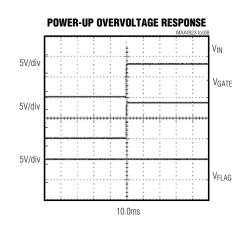








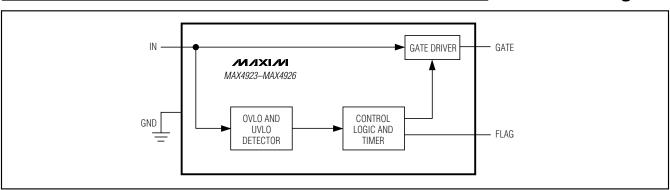




Pin Description

PIN	NAME FUNCTION					
1	IN	Voltage Input. IN is both the power-supply input and the overvoltage/undervoltage sense input. Bypass IN to GND with a 1µF ceramic capacitor as close as possible to the device to enable ±15kV (HBM) ESD protection on IN.				
2	GND	Ground				
3	FLAG	Fault Indication Open-Drain Output. FLAG deasserts high during undervoltage and overvoltage lockout conditions. FLAG asserts low during normal operation.				
4	GATE	pFET Gate Drive Output. GATE is driven high during a fault condition to turn off the external pFET. When V _{UVLO} < V _{IN} < V _{OVLO} , GATE is driven low and the external pFET is turned on.				
5, 6	N.C.	No Connection. Not internally connected. Leave N.C. unconnected.				

Functional Diagram



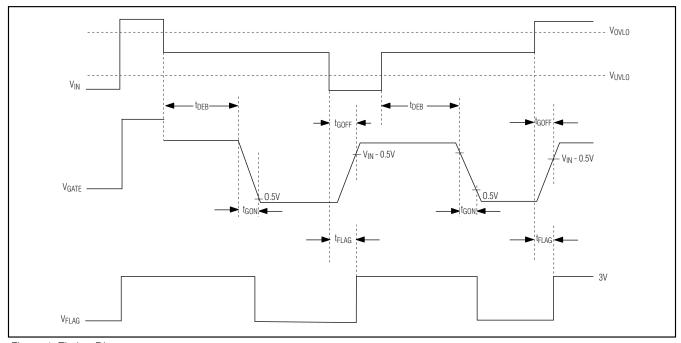


Figure 1. Timing Diagram

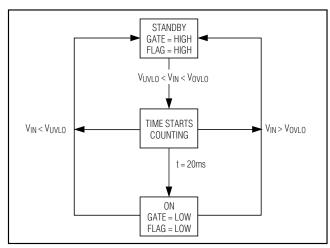


Figure 2. State Machine

Detailed Description

The MAX4923-MAX4926 overvoltage protection controllers protect low-voltage systems against high-voltage faults of up to +28V when used with a -30V pFET. When the input voltage exceeds the OVLO threshold, these devices turn off the external pFET to prevent damage to protected components.

The typical overvoltage trip level is set to 7.18V (MAX4923), 6.16V (MAX4924), 5.65V (MAX4925), and 4.46V (MAX4926). When the supply drops below the UVLO threshold, the devices turn off the external pFET.

IN is ESD protected to $\pm 15 kV$ (Human Body Model) when bypassed with a 1µF ceramic capacitor to ground.

Undervoltage Lockout (UVLO)

The MAX4923–MAX4926 have a fixed 2.44V (typ) UVLO level. When V_{IN} is less than V_{UVLO} , GATE is high and FLAG is high.

Overvoltage Lockout (OVLO)

The MAX4923 has a 7.18V (typ) OVLO; the MAX4924 has a 6.16V (typ) OVLO; the MAX4925 has a 5.65V (typ) OVLO; and the MAX4926 has a 4.46V (typ) OVLO. When V_{IN} is greater than V_{OVLO} , GATE is high and FLAG is high.

FLAG Output

The open-drain FLAG output is used to signal to the host system that there is a fault with the input voltage. FLAG goes high during an overvoltage or undervoltage fault. Connect a pullup resistor from FLAG to the logic I/O voltage of the host system.

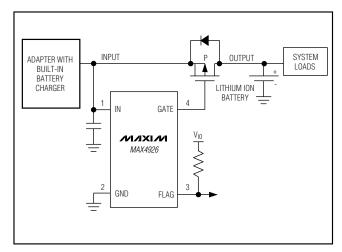


Figure 3. MAX4926 Typical Operating Circuit

Device Operation

The MAX4923–MAX4926 have an on-board state machine to control device operation. A flowchart is shown in Figure 2. At initial power up, if $V_{\text{IN}} < V_{\text{UVLO}}$ or if $V_{\text{IN}} > V_{\text{OVLO}}$, both GATE and FLAG are high. When $V_{\text{UVLO}} < V_{\text{IN}} < V_{\text{OVLO}}$, an internal timer starts counting and the device enters its on state after a 20ms delay. At any time if V_{IN} drops below V_{UVLO} or above V_{OVLO} , both GATE and FLAG transition high.

_Application Information

MAX4926 Application

In a typical application for the MAX4926, an external adapter with built-in battery charger is connected to IN and a battery is connected to the drain of the external FET. When the adapter is unplugged, IN is directly connected to the battery through the external FET. Since the battery voltage is typically greater than VUVLO, the GATE voltage stays low and the device remains powered by the battery.

MOSFET Selection

The MAX4923–MAX4926 are designed for use with either a single pFET or dual pFETs in parallel. MOSFETs with R_{DS(ON)} specified for a V_{GS} of -4.5V are recommended. For input supplies near the UVLO maximum of 2.5V, use a MOSFET specified for a lower V_{GS} voltage. Also, the V_{DS} must be -30V and the V_{GS} (max) must be higher than the V_{OVLO} (max) for the MOSFET to withstand the full +28V input range of the MAX4923–MAX4926.

Table 1. MOSFETS Suggestions

PART	CONFIGURATON/ PACKAGE	V _{DS} MAX (V)	R _{ON} MAX (m Ω) at V _{GS} = -4.5V	MANUFACTURER
Si3993DV	Dual/TSOP-6	-30	245 each	
Si1433DH	Single/SOT-363	-30	260	
Si3983DV	Dual/TSOP-6	-20	110 each	Vishay Siliconix
Si1413DH	Single/SOT-363	-20	115	www.vishay.com
Si5933DC	Dual/1206-8	-20	110 each	
Si6991DQ	Dual/TSSOP-8	-30	68 each	

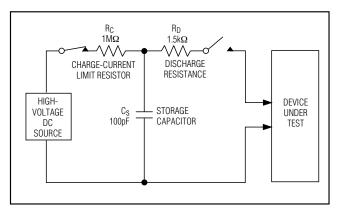


Figure 4. Human Body ESD Test Model

AMPERES 36.8% 10% 0 1 TIME CURRENT WAVEFORM

Figure 5. Human Body Model Current Waveform

IN Bypass Consideration

For most applications, bypass IN to GND with a 1µF ceramic capacitor. If the power source has significant inductance due to long lead length, take care to prevent overshoots due to the LC tank circuit and provide protection if necessary to prevent exceeding the 30V absolute maximum rating on IN.

ESD Test Conditions

The MAX4923–MAX4926 are ESD protected to $\pm 15 \text{kV}$ (typ) Human Body Model on IN when IN is bypassed to ground with a 1µF ceramic capacitor as close as possible to IN.

Human Body Model

Figure 4 shows the Human Body Model and Figure 5 shows the current waveform it generates when discharged into a low impedance. This model consists of a 100pF capacitor charged to the ESD voltage of interest that is then discharged into the device through a $1.5 \mathrm{k}\Omega$ resistor.

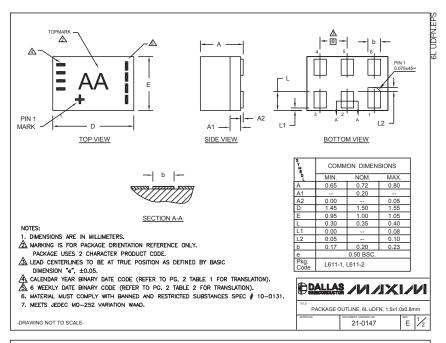
_Chip Information

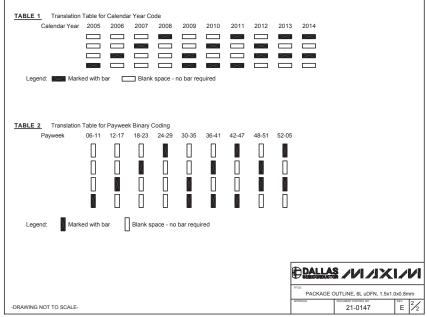
PROCESS: BICMOS

6 ______ /V|/X|/M

Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information go to www.maxim-ic.com/packages.)





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